

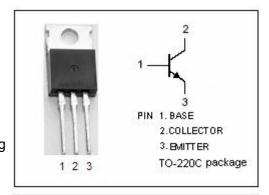
# **isc Silicon NPN Power Transistor**

## **DESCRIPTION**

- · Collector-Emitter Sustaining Voltage-
  - : V<sub>CEO(SUS)</sub>= 450V(Min.)
- · High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

• Designed for use in high-voltage, high-speed, power switching regulators, converters, inverters, motor control system.

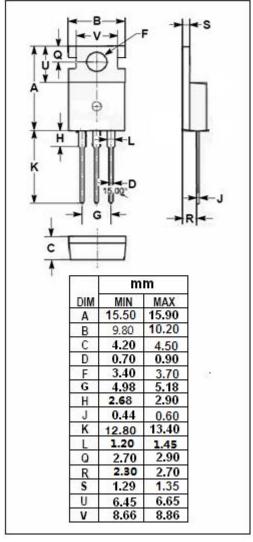


## ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CES</sub>	Collector-Emitter Voltage	1000	V
Vceo	Collector-Emitter Voltage	450	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
Ic	Collector Current-Continuous	2	Α
I <sub>CM</sub>	Collector Current-Peak	3	Α
I <sub>B</sub>	Base Current	0.75	Α
I <sub>BM</sub>	Base Current-Peak	1	Α
Pc	Collector Power Dissipation @T <sub>C</sub> =25℃	40	W
T <sub>j</sub>	Junction Temperature	150	$^{\circ}\!$
T <sub>stg</sub>	Storage Temperature Range	-65~150	$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.5	°C/W





## **isc Silicon NPN Power Transistor**

BUX85

#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	450			V
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 0.3A; I <sub>B</sub> = 0.03A			0.8	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 0.2A			1.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 0.2A			1.1	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 1000V; I <sub>E</sub> = 0 V <sub>CB</sub> = 1000V; I <sub>E</sub> = 0;T <sub>C</sub> =125°C			0.2 1.5	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 9V; I <sub>C</sub> = 0			10	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 5V	20		100	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 5V	15			



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